Product data sheet

1. General description

Ultrafast power diode.

2. Features and benefits

- Fast switching
- Very low on-state loss
- Low leakage current

3. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Notes		Values		Unit
V_{RRM}	repetitive peak reverse voltage		[1]		600		V
I _{F(AV)}	average forward current	δ = 0.5; square-wave pulse	[2]		30		Α
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static ch	Static characteristics						
V _F	forward voltage	I _F = 30 A; T _j = 25 °C	[2]	-	1.18	1.55	V
Dynamic characteristics							
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 100 \text{ A/}\mu\text{s}$; $T_j = 25 \text{ °C}$	[2]	-	42	-	ns

4. Ordering information

Table 2. Ordering information

Product type	Orderable part number	Description	Packing method
WB30FV60AL	WB30FV60ALZ	Bare die on wafer	Unsawn wafer, Vacuum packing

5. Limiting values

Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V_{RRM}	repetitive peak reverse voltage		[1]	600	V
V_{RWM}	crest working reverse voltage		[1]	600	V
V_R	reverse voltage	DC	[1]	600	V
I _{F(AV)}	average forward current	δ = 0.5; square-wave pulse	[2]	30	А
I _{FRM}	repetitive peak forward current	δ = 0.5; t_p = 25 μ s; square-wave pulse	[2]	60	А
I _{FSM}	non-repetitive peak forward	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	[2]	290	А
	current	t_p = 8.3 ms; $T_{j(init)}$ = 25 °C;sine-wave pulse	[2]	330	А
T _j	junction temperature			-40 to 175	°C

6. Characteristics

Table 4. Characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static cha	Static characteristics						
V _F	forward voltage	I _F = 30 A; T _j = 25 °C	[2]	-	1.18	1.55	V
		I _F = 30 A; T _j = 150 °C	[2]	-	0.98	-	V
I _R rever	reverse current	V _R = 600 V; T _j = 25 °C	[1]	-	2	10	μA
		V _R = 600 V; T _j = 125 °C	[2]	-	-	500	μA
Dynamic	Dynamic characteristics						
Q _r	recovered charge	$I_F = 30 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}$	[2]	-	272	-	nC
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 50 \text{ A}/\mu\text{s};$ $T_j = 25 ^{\circ}\text{C}$	[2]	-	42	-	ns
		$I_F = 30 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}$	[2]	-	65	-	ns

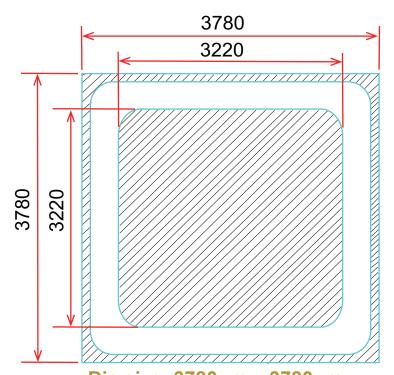
Notes:

^[1] means that parameter are 100% test at T_{amb} = 25°C.

^[2] means that the guaranteed ratings and parameter limits will depend on the assembled structure. When correctly assembled with suitable die bonding and wire bonding, the device will have ratings and characteristics guaranteed in this data sheet, similar to the assembled devices.

MECHANICAL SPECIFICATIONS			
Chip size	3.78 x 3.78	mm²	
Anode pad size	3.22 x 3.22	mm²	
Area total / active	14.29 / 10.37	mm²	
Thickness	300	μm	
Wafer size	125	mm	
Scribe line	80	μm	
Max possible chips per wafer	761	pcs	
Passivation	Glass/Trough		
Front metal	AI (5.5)	μm	
Back metal	Ti/Ni/Ag (0.1/0.3/0.15)	μm	

CHIP LAYOUT



Die size: 3780μm x 3780μm Bond pad size: 3220μm x 3220μm

7. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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Ultrafast power diode - Bare die

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WB30FV60AL

Ultrafast power diode - Bare die

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